

BD241A/B/C/BD242A/B/C

THERMAL DATA

R _{thj-case}	Thermal Resistance Junction-case	Max	3.13	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient	Max	62.5	°C/W

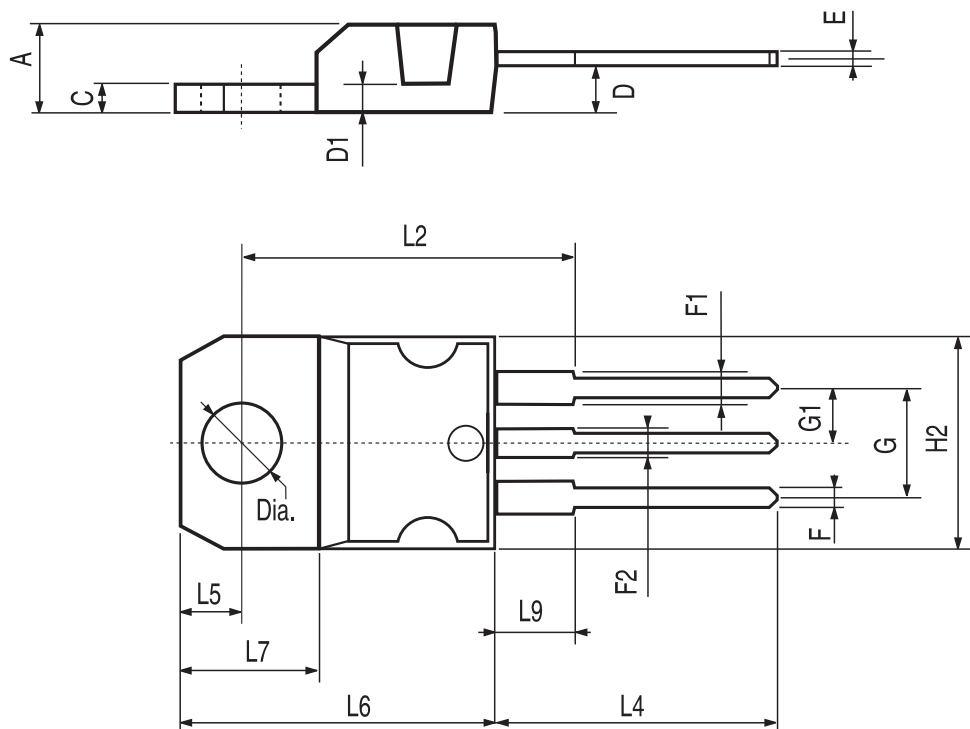
ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = rated V _{CEO}			0.2	mA
I _{CEO}	Collector Cut-off Current (I _B = 0)	for BD241A/BD242A V _{CE} = 30 V for BD241B/BD242B V _{CE} = 60 V for BD241C/BD242C V _{CE} = 60 V			0.3 0.3 0.3	mA mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	mA
V _{CEO(sus)*}	Collector-Emitter Sustaining Voltage	I _C = 30 mA for BD241A/BD242A for BD241B/BD242B for BD241C/BD242C	60 80 100			V V V
V _{CE(sat)*}	Collector-Emitter Saturation Voltage	I _C = 3 A I _B = 0.6 A			1.2	V
V _{BE*}	Base-Emitter Voltage	I _C = 3 A V _{CE} = 4 V			1.8	V
h _{FE*}	DC Current Gain	I _C = 1 A V _{CE} = 4 V I _C = 3 A V _{CE} = 4 V	25 10			
h _{fe}	Small Signal Current Gain	I _C = 0.5 A V _{CE} = 10 V f = 1MHz I _C = 0.5 A V _{CE} = 10 V f = 1KHz	3 20			

* Pulsed: Pulse duration = 300 μs, duty cycle ≤ 2 %
For PNP types voltage and current values are negative.
For the characteristics curves see TIP31/TIP32 series.

TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



P011C

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